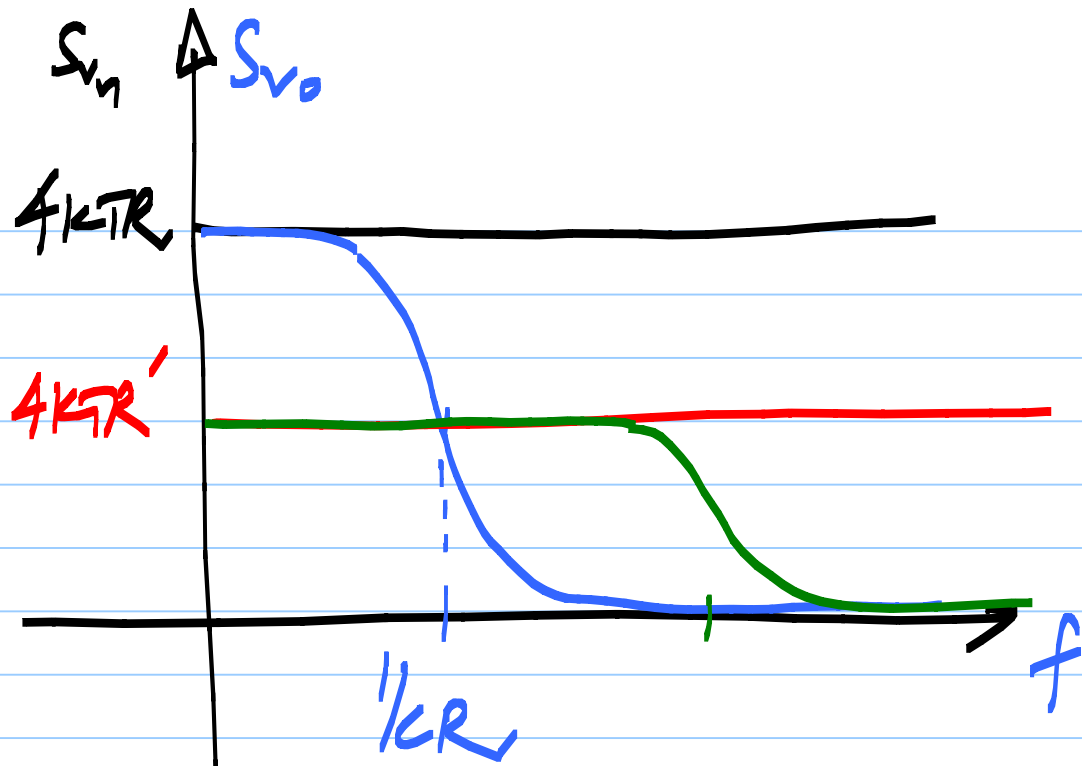


$$\frac{V_o}{V_i} = \frac{1}{1 + sCR}$$

$$\frac{V_o}{V_w} = \frac{1}{1 + sCR} ;$$



$$S_{v0} = S_{vn} \frac{1}{1 + 4\pi^2 f^2 CR^2}$$

$$V_o^2 = \int_0^{\infty} \frac{4kTR}{1 + 4\pi^2 f^2 C^2 R^2} df = \frac{4kTR}{2\pi CR} \cdot \tan^{-1}\left(\frac{2\pi f CR}{1}\right) \Big|_0^{\infty}$$

$\frac{kT}{C}$ Variance
 mean-squared value

$C = 10 \text{ fF}$

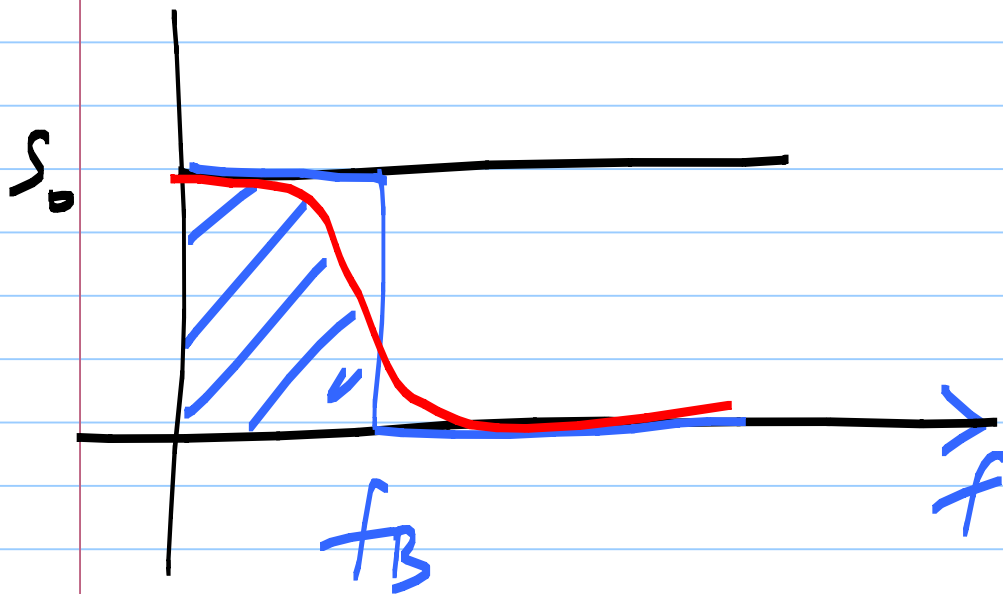
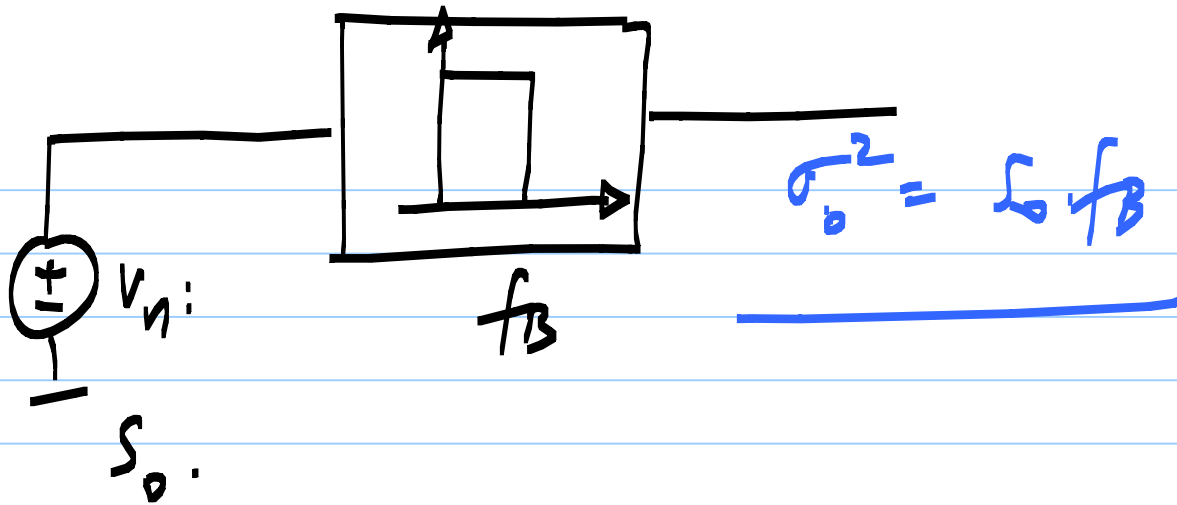
rms value:

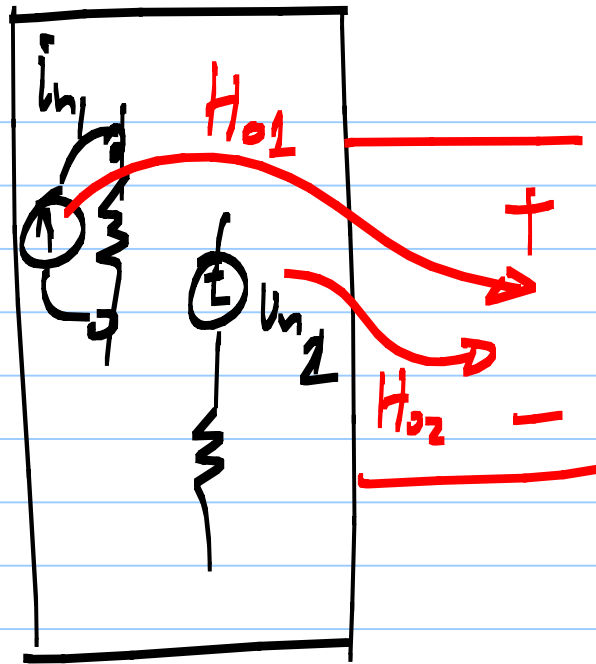
$$\sqrt{\frac{kT}{C}} = \sqrt{\frac{4 \cdot 10^{-21}}{5 \cdot 10^{-12}}} \text{ V} = \sqrt{40 \cdot 10^{-5}} \text{ V}$$

$4kTR \cdot \left[\frac{1}{2\pi CR} \cdot \frac{\pi}{2} \right]$

$\left\{ \frac{\pi}{2} \cdot f_{-3dB} \right\}$ Noise BW of a 1st ord. LPT

63 mV 630 pV



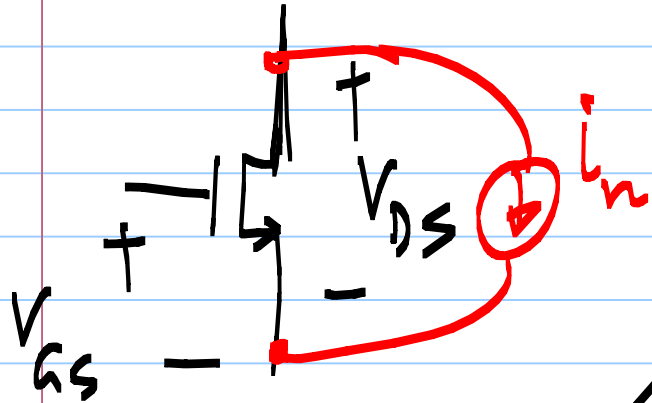


$$S_{i_{n1}} \cdot |H_{o1}|^2 + S_{v_{n2}} \cdot |H_{o2}|^2 + \dots$$

MOS transistor

$$I_D = \frac{\mu C_{ox}}{2} \frac{W}{L} (V_{GS} - V_T)^2$$

$V_{GS} > V_T$
 $V_{DS} > V_{GS} - V_T$



Thermal noise

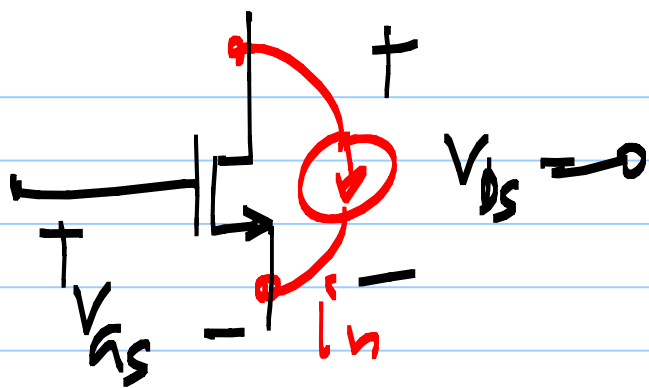
$$S_{i_n} = \frac{8}{3} kT \cdot g_m \quad \left. \vphantom{S_{i_n}} \right\} \text{White}$$

Noise spectral
density in saturation
region

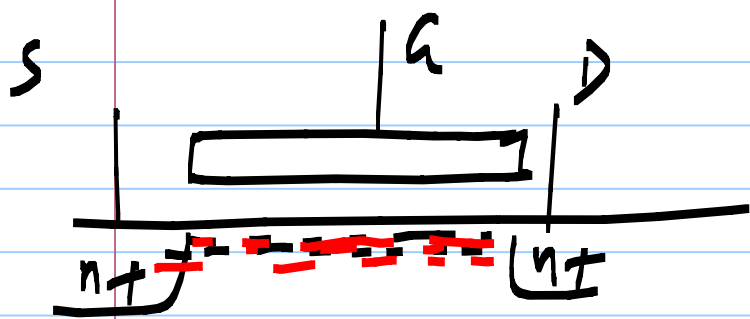
$$S_{i_R} = 4 \cdot kT \cdot G$$

Conductance

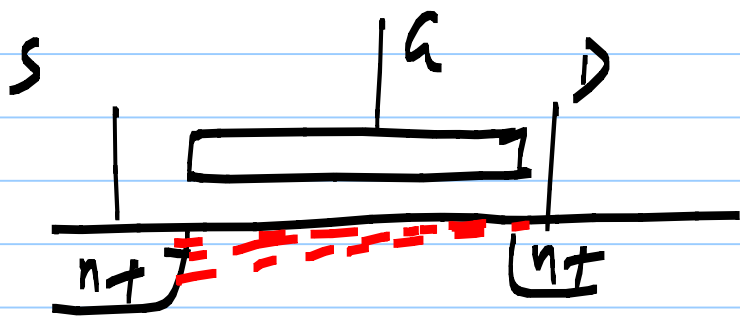
Triode region



$S_{i_n} = 4kT \cdot g_{ds} |_{V_{ds}=0}$



@ $V_{ds} = 0$



@ $V_{ds} > 0$

$$g_m (\text{sat. region}) = \mu C_{ox} \frac{W}{L} (V_{GS} - V_T)$$

$$I_{DS} (V_{DS} = 0) = \mu C_{ox} \frac{W}{L} (V_{GS} - V_T)$$

$$S_{in} = 4kT \cdot \frac{\mu |Q_{in}|}{L^2}$$

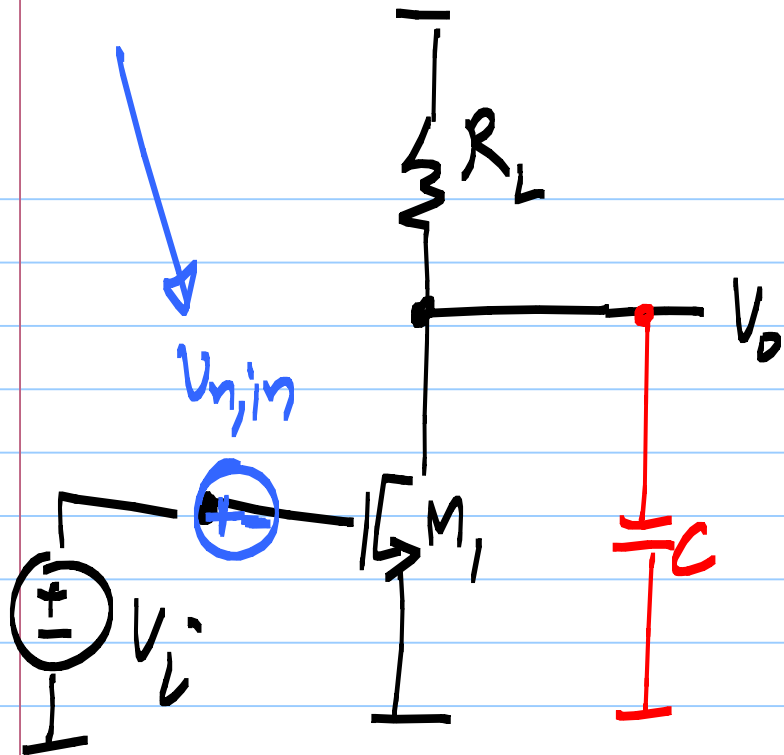
Inversion charge @ $V_{DS} = 0$

$$C_{ox} \cdot W \cdot L \cdot (V_{GS} - V_T)$$

$$4kT \cdot$$

$$\mu C_{ox} \frac{W}{L} (V_{GS} - V_T)$$

$$\frac{2}{3} C_{ox} W L (V_{GS} - V_T)$$

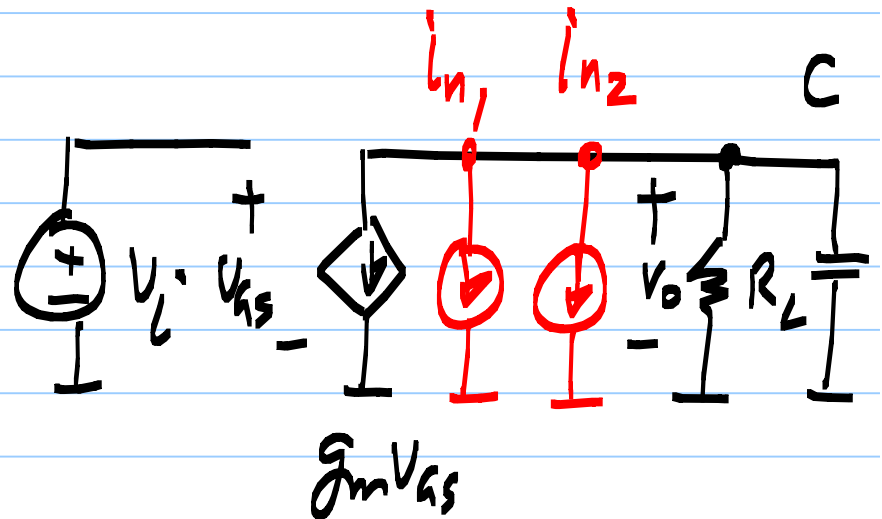


M_1 : saturation,

g_m

1. Find S_{v_o}

2. o/p loaded by C , find the integrated o/p noise (variance)



$$\frac{V_o}{i_{n1}} = \frac{V_o}{i_{n2}} = R_L \left[\frac{R_L}{1 + 5CR_L} \right]$$

$$S_{V_o} = S_{i_{n1}} \left| \frac{V_o}{i_{n1}} \right|^2 + S_{i_{n2}} \left| \frac{V_o}{i_{n2}} \right|^2$$

$$= \frac{8}{3} kT g_m R_L^2 + \frac{4kT}{R_L} R_L^2 =$$

$$\left[\frac{8}{3} kT g_m + \frac{4kT}{R_L} \right] R_L^2 = \frac{8}{3} \frac{kT}{g_m} (g_m R_L)^2 \left[1 + \frac{3}{2g_m R_L} \right]$$

from R_L from M

M_1 R_L

$$\sigma_{v_o}^2 = \left[\frac{8}{3} kT g_m + \frac{4kT}{R_L} \right] R_L^2 \left[\frac{1}{4R_L C} \right]$$
